

TC74LVX74F, TC74LVX74FN, TC74LVX74FT

DUAL D-TYPE FLIP FLOP WITH PRESET AND CLEAR

The TC74LVX74 is a high speed CMOS D-FLIP FLOP fabricated with silicon gate C²MOS technology. Designed for use in 3.3 Volt systems, it achieves high speed operation while maintaining the CMOS low power dissipation. This device is suitable for low voltage and battery operated systems.

The signal level applied to the D INPUT is transferred to Q OUTPUT during the positive going transition of the CK pulse.

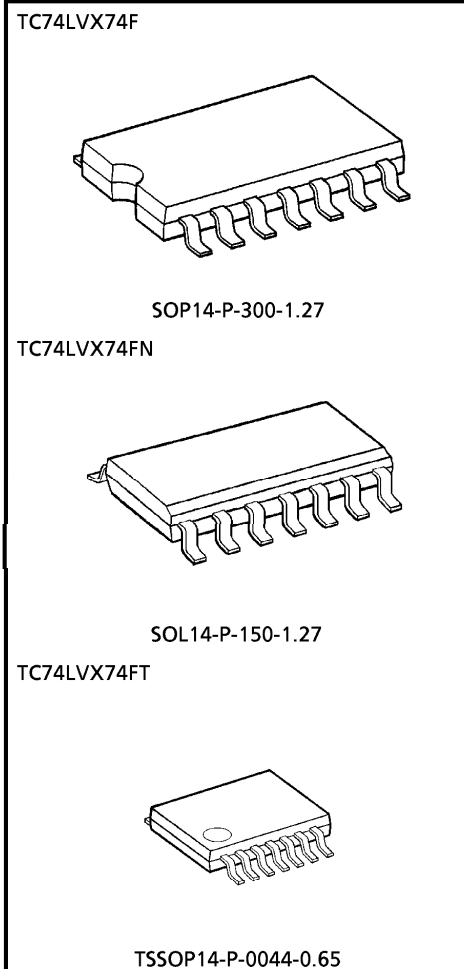
$\overline{\text{CLR}}$ and $\overline{\text{PR}}$ are independent of the CK and are accomplished by setting the appropriate input low.

An input protection circuit ensures that 0 to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

FEATURES

- High speed : $f_{\text{MAX}} = 145\text{MHz}$ (Typ.) ($V_{\text{CC}} = 3.3\text{V}$)
- Low power dissipation : $I_{\text{CC}} = 2\mu\text{A}$ (Max.) ($T_a = 25^\circ\text{C}$)
- Input voltage level : $V_{\text{IL}} = 0.8\text{V}$ (Max.) ($V_{\text{CC}} = 3\text{V}$)
 $V_{\text{IH}} = 2.0\text{V}$ (Min.) ($V_{\text{CC}} = 3\text{V}$)
- Power down protection is provided on all inputs.
- Balanced propagation delays : $t_{\text{PLH}} \approx t_{\text{PHL}}$
- Pin and function compatible with 74HC74

(Note) The JEDEC SOP (FN) is not available in Japan.

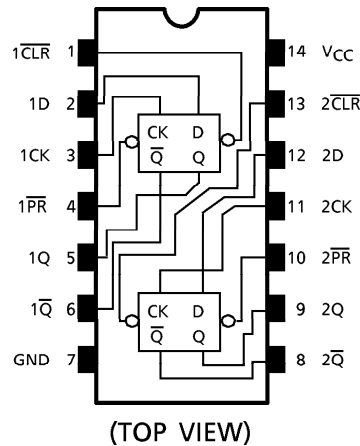


Weight
 SOP14-P-300-1.27 : 0.18g (Typ.)
 SOL14-P-150-1.27 : 0.12g (Typ.)
 TSSOP14-P-0044-0.65 : 0.06g (Typ.)

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PIN ASSIGNMENT

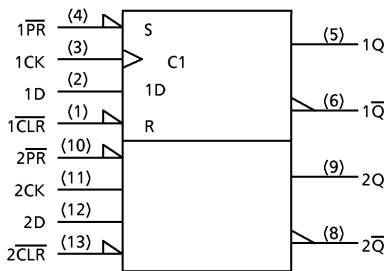


TRUTH TABLE

INPUTS				OUTPUTS		FUNCTION
CLR	PR	D	CK	Q	Q	
L	H	X	X	L	H	CLEAR
H	L	X	X	H	L	PRESET
L	L	X	X	H	H	—
H	H	L	↑	L	H	—
H	H	H	↑	H	L	—
H	H	X	⎯	Q _n	Q _n	NO CHANGE

X: Don't care

IEC LOGIC SYMBOL



MAXIMUM RATINGS

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage Range	V _{CC}	-0.5~7.0	V
DC Input Voltage	V _{IN}	-0.5~7.0	V
DC Output Voltage	V _{OUT}	-0.5~V _{CC} +0.5	V
Input Diode Current	I _{IK}	-20	mA
Output Diode Current	I _{OK}	±20	mA
DC Output Current	I _{OUT}	±25	mA
DC V _{CC} /Ground Current	I _{CC}	±50	mA
Power Dissipation	P _D	180	mW
Storage Temperature	T _{stg}	-65~150	°C

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- The information contained herein is subject to change without notice.

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	V_{CC}	2.0~3.6	V
Input Voltage	V_{IN}	0~5.5	V
Output Voltage	V_{OUT}	0~ V_{CC}	V
Operating Temperature	T_{opr}	-40~85	°C
Input Rise And Fall Time	dt/dv	0~100	ns/V

ELECTRICAL CHARACTERISTICS

DC characteristics

PARAMETER		SYM- BOL	TEST CONDITION		V _{CC} (V)	Ta = 25°C			Ta = -40~85°C		UNIT
						MIN.	TYP.	MAX.	MIN.	MAX.	
Input Voltage	“H” Level	V _{IH}			2.0	1.5	—	—	1.5	—	V
					3.0	2.0	—	—	2.0	—	
					3.6	2.4	—	—	2.4	—	
	“L” Level	V _{IL}			2.0	—	—	0.5	—	0.5	
					3.0	—	—	0.8	—	0.8	
					3.6	—	—	0.8	—	0.8	
Output Voltage	“H” Level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50μA	2.0	1.9	2.0	—	1.9	—	V
				I _{OH} = -50μA	3.0	2.9	3.0	—	2.9	—	
				I _{OH} = -4mA	3.0	2.58	—	—	2.48	—	
	“L” Level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50μA	2.0	—	0.0	0.1	—	0.1	
				I _{OL} = 50μA	3.0	—	0.0	0.1	—	0.1	
				I _{OL} = 4mA	3.0	—	—	0.36	—	0.44	
Input Leakage Current		I _{IN}	V _{IN} = 5.5V or GND		3.6	—	—	±0.1	—	±1.0	μA
Quiescent Supply Current		I _{CC}	V _{IN} = V _{CC} or GND		3.6	—	—	2.0	—	20.0	μA

TIMING REQUIREMENTS (Input $t_r = t_f = 3\text{ns}$)

PARAMETER	SYM-BOL	TEST CONDITION	V_{CC} (V)	$T_a = 25^\circ\text{C}$	$T_a = -40 \sim 85^\circ\text{C}$	UNIT
				LIMIT	LIMIT	
Minimum Pulse Width (CK)	t_W (L)		2.7	8.5	10.0	ns
	t_W (H)		3.3 ± 0.3	6.0	7.0	
Minimum Pulse Width (CLR, PR)	t_W (L)		2.7	8.5	10.0	ns
			3.3 ± 0.3	6.0	7.0	
Minimum Set-up Time	t_s		2.7	8.0	9.5	ns
			3.3 ± 0.3	5.5	6.5	
Minimum Hold Time	t_h		2.7	0.5	0.5	ns
			3.3 ± 0.3	0.5	0.5	
Minimum Removal Time (CLR, PR)	t_{rem}		2.7	6.5	7.5	ns
			3.3 ± 0.3	5.0	5.0	

AC characteristics (Input $t_r = t_f = 3\text{ns}$)

PARAMETER	SYM- BOL	TEST CONDITION			Ta = 25°C			Ta = - 40~85°C		UNIT
			V _{CC} (V)	C _L (pF)	MIN.	TYP.	MAX.	MIN.	MAX.	
Propagation Delay Time (CK-Q, $\overline{Q}$)	t _{pLH}		2.7	15	—	7.3	15.0	1.0	18.5	ns
				50	—	9.8	18.5	1.0	22.0	
	t _{pHL}		3.3 ± 0.3	15	—	5.7	9.7	1.0	11.5	
				50	—	8.2	13.2	1.0	15.0	
Propagation Delay Time ($\overline{\text{CLR}}$, $\overline{\text{PR-Q}}$, $\overline{Q}$)	t _{pLH}		2.7	15	—	8.4	15.6	1.0	18.5	ns
				50	—	10.9	19.1	1.0	22.0	
	t _{pHL}		3.3 ± 0.3	15	—	6.6	10.1	1.0	12.0	
				50	—	9.1	13.6	1.0	15.5	
Maximum Clock Frequency	f _{MAX}		2.7	15	55	135	—	50	—	MHz
				50	45	60	—	40	—	
			3.3 ± 0.3	15	95	145	—	80	—	
				50	60	85	—	50	—	
Output To Output Skew	t _{osLH}	(Note 1)	2.7	50	—	—	1.5	—	1.5	ns
	t _{osHL}		3.3 ± 0.3	50	—	—	1.5	—	1.5	
Input Capacitance	C _{IN}	(Note 2)			—	4	10	—	10	pF
Power Dissipation Capacitance	C _{PD}	(Note 3)			—	25	—	—	—	pF

(Note 1) Parameter guaranteed by design.

$$(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$$

(Note 2) Parameter guaranteed by design.

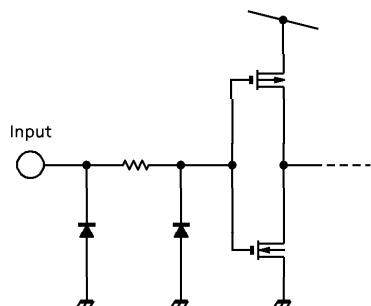
(Note 3) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation :

$$I_{CC}(\text{opr.}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2 \text{ (per F/F)}$$

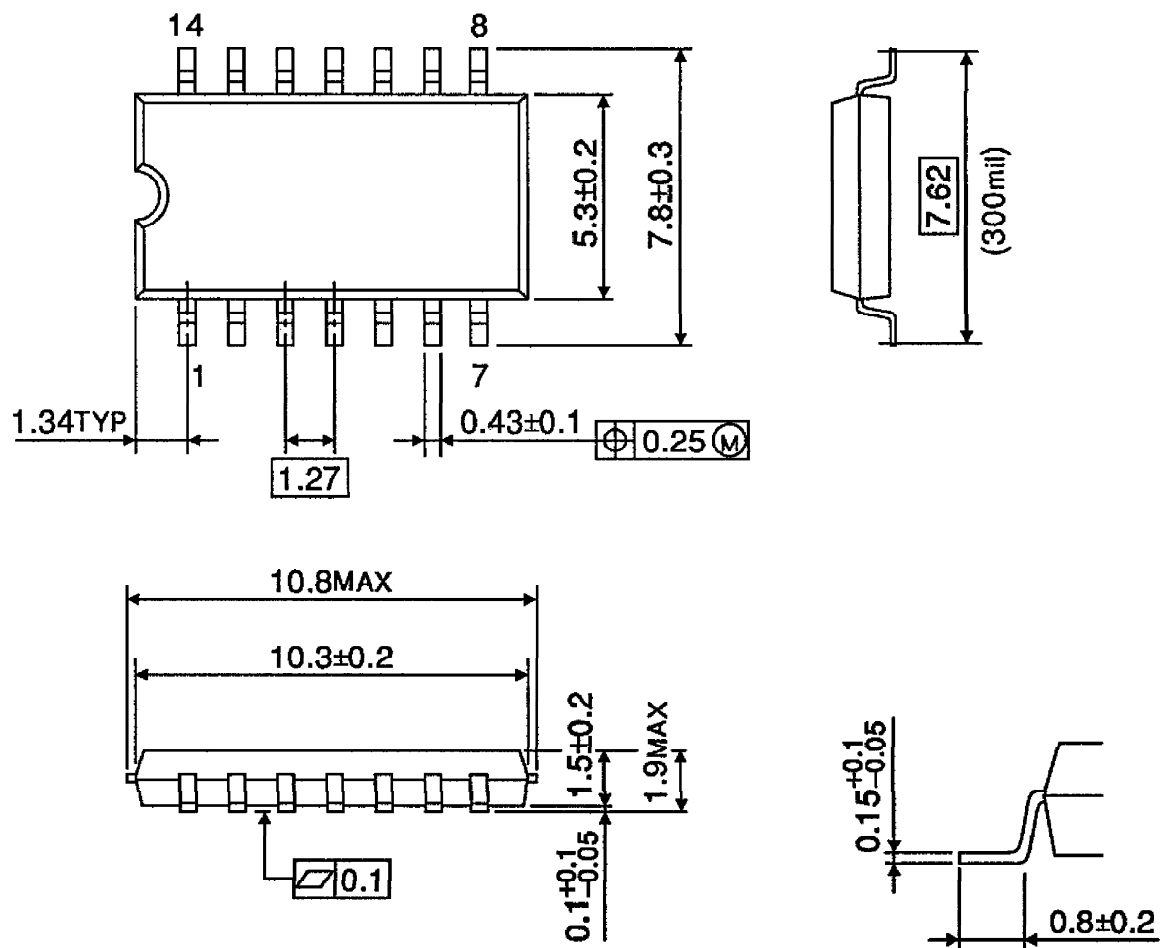
Noise characteristics (Ta = 25°C, Input $t_r = t_f = 3\text{ns}$, C_L = 50pF)

PARAMETER	SYMBOL	TEST CONDITION	V _{CC} (V)	TYP.	LIMIT	UNIT
Quiet Output Maximum Dynamic V _{OL}	V _{OLP}		3.3	0.3	0.5	V
Quiet Output Minimum Dynamic V _{OL}	V _{OLV}		3.3	-0.3	-0.5	V
Minimum High Level Dynamic Input Voltage	V _{IHD}		3.3	—	2.0	V
Maximum Low Level Dynamic Input Voltage	V _{ILD}		3.3	—	0.8	V

INPUT EQUIVALENT CIRCUIT

OUTLINE DRAWING
SOP14-P-300-1.27

Unit : mm



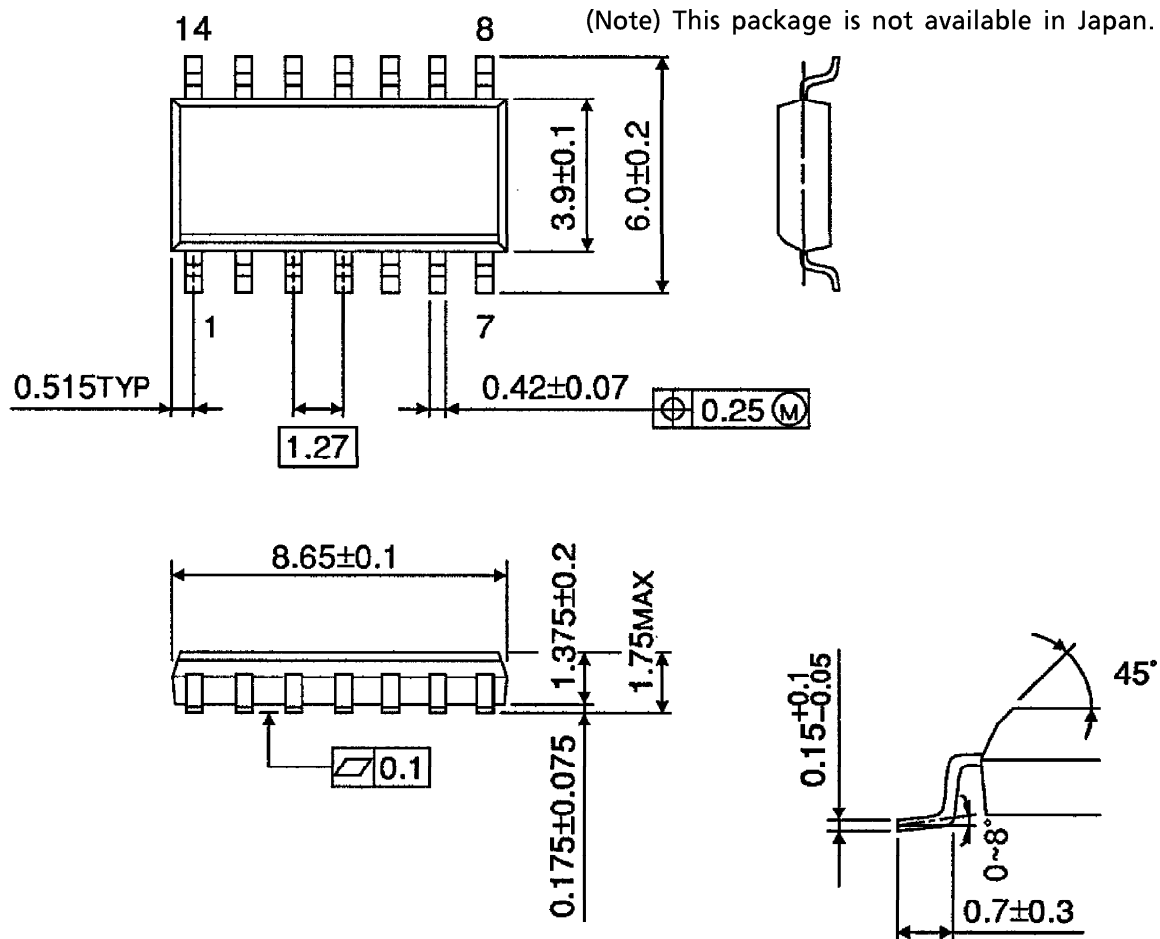
Weight : 0.18g (Typ.)

OUTLINE DRAWING

SOL14-P-150-1.27

Unit : mm

(Note) This package is not available in Japan.

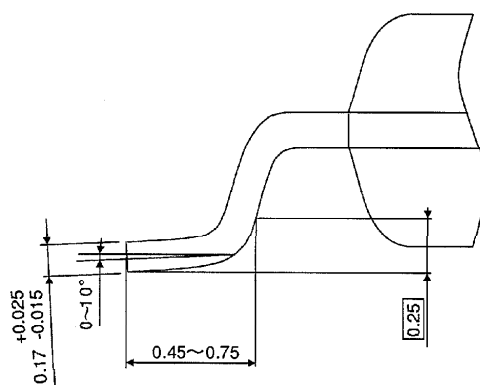
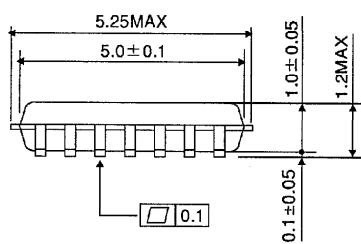
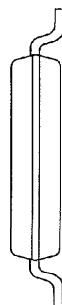
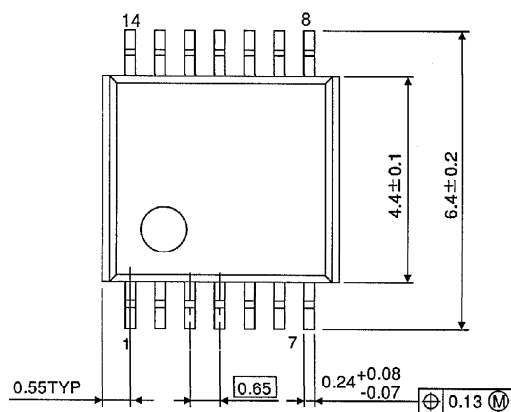


Weight : 0.12g (Typ.)

OUTLINE DRAWING

TSSOP14-P-0044-0.65

Unit : mm



Weight : 0.06g (Typ.)